## Chao Xie

## List of Publications by Citations

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76
papers

4,933
citations

37
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g-index

79
ext. papers

5,818
ext. citations

8.8
avg, IF

L-index

#	Paper	IF	Citations
76	Photodetectors Based on Two-Dimensional Layered Materials Beyond Graphene. <i>Advanced Functional Materials</i> , <b>2017</b> , 27, 1603886	15.6	406
75	Monolayer graphene/germanium Schottky junction as high-performance self-driven infrared light photodetector. <i>ACS Applied Materials &amp; Distriction as</i> 1, 9362-6	9.5	280
74	Monolayer graphene film on ZnO nanorod array for high-performance Schottky junction ultraviolet photodetectors. <i>Small</i> , <b>2013</b> , 9, 2872-9	11	236
73	Core-shell heterojunction of silicon nanowire arrays and carbon quantum dots for photovoltaic devices and self-driven photodetectors. <i>ACS Nano</i> , <b>2014</b> , 8, 4015-22	16.7	216
7 <sup>2</sup>	Fast, Self-Driven, Air-Stable, and Broadband Photodetector Based on Vertically Aligned PtSe2/GaAs Heterojunction. <i>Advanced Functional Materials</i> , <b>2018</b> , 28, 1705970	15.6	207
71	Ultrasensitive broadband phototransistors based on perovskite/organic-semiconductor vertical heterojunctions. <i>Light: Science and Applications</i> , <b>2017</b> , 6, e17023	16.7	203
70	Recent Progress in Solar-Blind Deep-Ultraviolet Photodetectors Based on Inorganic Ultrawide Bandgap Semiconductors. <i>Advanced Functional Materials</i> , <b>2019</b> , 29, 1806006	15.6	189
69	Controlled Synthesis of 2D Palladium Diselenide for Sensitive Photodetector Applications. <i>Advanced Functional Materials</i> , <b>2019</b> , 29, 1806878	15.6	187
68	Flexible Photodetectors Based on Novel Functional Materials. <i>Small</i> , <b>2017</b> , 13, 1701822	11	185
67	Ultrathin and flexible perovskite solar cells with graphene transparent electrodes. <i>Nano Energy</i> , <b>2016</b> , 28, 151-157	17.1	158
66	Perovskite-Based Phototransistors and Hybrid Photodetectors. <i>Advanced Functional Materials</i> , <b>2020</b> , 30, 1903907	15.6	127
65	Graphene/Semiconductor Hybrid Heterostructures for Optoelectronic Device Applications. <i>Nano Today</i> , <b>2018</b> , 19, 41-83	17.9	124
64	Ultrafast, Self-Driven, and Air-Stable Photodetectors Based on Multilayer PtSe/Perovskite Heterojunctions. <i>Journal of Physical Chemistry Letters</i> , <b>2018</b> , 9, 1185-1194	6.4	119
63	Light trapping and surface plasmon enhanced high-performance NIR photodetector. <i>Scientific Reports</i> , <b>2014</b> , 4, 3914	4.9	115
62	Surface passivation and band engineering: a way toward high efficiency grapheneplanar Si solar cells. <i>Journal of Materials Chemistry A</i> , <b>2013</b> , 1, 8567	13	108
61	High-efficiency graphene/Si nanoarray Schottky junction solar cells via surface modification and graphene doping. <i>Journal of Materials Chemistry A</i> , <b>2013</b> , 1, 6593	13	107
60	Monolayer graphene film/silicon nanowire array Schottky junction solar cells. <i>Applied Physics Letters</i> , <b>2011</b> , 99, 133113	3.4	107

## (2018-2019)

59	Sensitive Deep Ultraviolet Photodetector and Image Sensor Composed of Inorganic Lead-Free CsCuI Perovskite with Wide Bandgap. <i>Journal of Physical Chemistry Letters</i> , <b>2019</b> , 10, 5343-5350	6.4	99
58	Perovskite/Poly(3-hexylthiophene)/Graphene Multiheterojunction Phototransistors with Ultrahigh Gain in Broadband Wavelength Region. <i>ACS Applied Materials &amp; Description of the Property of the Photography of the Property of</i>	9.5	88
57	Graphene Transparent Conductive Electrodes for Highly Efficient Silicon Nanostructures-Based Hybrid Heterojunction Solar Cells. <i>Journal of Physical Chemistry C</i> , <b>2013</b> , 117, 11968-11976	3.8	85
56	High-efficiency, air stable graphene/Si micro-hole array Schottky junction solar cells. <i>Journal of Materials Chemistry A</i> , <b>2013</b> , 1, 15348	13	74
55	Surface induced negative photoconductivity in p-type ZnSe: Bi nanowires and their nano-optoelectronic applications. <i>Journal of Materials Chemistry</i> , <b>2011</b> , 21, 6736		73
54	Surface plasmon resonance enhanced highly efficient planar silicon solar cell. <i>Nano Energy</i> , <b>2014</b> , 9, 112	-1 <del>7</del> .0	69
53	Aluminium-doped n-type ZnS nanowires as high-performance UV and humidity sensors. <i>Journal of Materials Chemistry</i> , <b>2012</b> , 22, 6856		69
52	PdSe2 Multilayer on Germanium Nanocones Array with Light Trapping Effect for Sensitive Infrared Photodetector and Image Sensing Application. <i>Advanced Functional Materials</i> , <b>2019</b> , 29, 1900849	15.6	66
51	High-gain visible-blind UV photodetectors based on chlorine-doped n-type ZnS nanoribbons with tunable optoelectronic properties. <i>Journal of Materials Chemistry</i> , <b>2011</b> , 21, 12632		62
50	Recent advances in the fabrication of graphene InO heterojunctions for optoelectronic device applications. <i>Journal of Materials Chemistry C</i> , <b>2018</b> , 6, 3815-3833	7.1	61
49	High-performance broadband heterojunction photodetectors based on multilayered PtSe directly grown on a Si substrate. <i>Nanoscale</i> , <b>2018</b> , 10, 15285-15293	7.7	61
48	Schottky solar cells based on graphene nanoribbon/multiple silicon nanowires junctions. <i>Applied Physics Letters</i> , <b>2012</b> , 100, 193103	3.4	59
47	One-dimensional CuO nanowire: synthesis, electrical, and optoelectronic devices application. <i>Nanoscale Research Letters</i> , <b>2014</b> , 9, 637	5	51
46	TiO2 Nanotube Array/Monolayer Graphene Film Schottky Junction Ultraviolet Light Photodetectors. <i>Particle and Particle Systems Characterization</i> , <b>2013</b> , 30, 630-636	3.1	49
45	Ferroelectric-Driven Performance Enhancement of Graphene Field-Effect Transistors Based on Vertical Tunneling Heterostructures. <i>Advanced Materials</i> , <b>2016</b> , 28, 10048-10054	24	45
44	Tuning the electrical transport properties of n-type CdS nanowires via Ga doping and their nano-optoelectronic applications. <i>Physical Chemistry Chemical Physics</i> , <b>2011</b> , 13, 14663-7	3.6	44
43	Enhanced performance of perovskite/organic-semiconductor hybrid heterojunction photodetectors with the electron trapping effects. <i>Journal of Materials Chemistry C</i> , <b>2018</b> , 6, 1338-1342	7.1	43
42	Silicon/Perovskite Core-Shell Heterojunctions with Light-Trapping Effect for Sensitive Self-Driven Near-Infrared Photodetectors. <i>ACS Applied Materials &amp; mp; Interfaces</i> , <b>2018</b> , 10, 27850-27857	9.5	39

41	Amplified Spontaneous Emission from OrganicIhorganic Hybrid Lead Iodide Perovskite Single Crystals under Direct Multiphoton Excitation. <i>Advanced Optical Materials</i> , <b>2016</b> , 4, 1053-1059	8.1	39
40	A high-performance near-infrared light photovoltaic detector based on a multilayered PtSe2/Ge heterojunction. <i>Journal of Materials Chemistry C</i> , <b>2019</b> , 7, 5019-5027	7.1	38
39	The effect of plasmonic nanoparticles on the optoelectronic characteristics of CdTe nanowires. <i>Small</i> , <b>2014</b> , 10, 2645-52	11	37
38	p-CdTe nanoribbon/n-silicon nanowires array heterojunctions: photovoltaic devices and zero-power photodetectors. <i>CrystEngComm</i> , <b>2012</b> , 14, 7222	3.3	36
37	Inorganic CsBi3I10 perovskite/silicon heterojunctions for sensitive, self-driven and air-stable NIR photodetectors. <i>Journal of Materials Chemistry C</i> , <b>2019</b> , 7, 863-870	7.1	34
36	Ultrahigh Mobility of p-Type CdS Nanowires: Surface Charge Transfer Doping and Photovoltaic Devices. <i>Advanced Energy Materials</i> , <b>2013</b> , 3, 579-583	21.8	34
35	Bilayer graphene based surface passivation enhanced nano structured self-powered near-infrared photodetector. <i>Optics Express</i> , <b>2015</b> , 23, 4839-46	3.3	33
34	Graphene-Assisted Growth of Patterned Perovskite Films for Sensitive Light Detector and Optical Image Sensor Application. <i>Small</i> , <b>2019</b> , 15, e1900730	11	31
33	Nano-Schottky barrier diodes based on Sb-doped ZnS nanoribbons with controlled p-type conductivity. <i>Applied Physics Letters</i> , <b>2011</b> , 98, 123117	3.4	31
32	Polymeric Carbon Nitride Nanosheets/Graphene Hybrid Phototransistors with High Responsivity. <i>Advanced Optical Materials</i> , <b>2016</b> , 4, 555-561	8.1	28
31	Patterned growth of EGa2O3 thin films for solar-blind deep-ultraviolet photodetectors array and optical imaging application. <i>Journal of Materials Science and Technology</i> , <b>2021</b> , 72, 189-196	9.1	28
30	Asymmetric Contact-Induced Self-Driven Perovskite-Microwire-Array Photodetectors. <i>Advanced Electronic Materials</i> , <b>2019</b> , 5, 1900135	6.4	27
29	ZnSe nanoribbon/Si nanowire pl heterojunction arrays and their photovoltaic application with graphene transparent electrodes. <i>Journal of Materials Chemistry</i> , <b>2012</b> , 22, 22873		26
28	A Highly Sensitive Perovskite/Organic Semiconductor Heterojunction Phototransistor and Its Device Optimization Utilizing the Selective Electron Trapping Effect. <i>Advanced Optical Materials</i> , <b>2019</b> , 7, 1900272	8.1	25
27	Doping dependent crystal structures and optoelectronic properties of n-type CdSe:Ga nanowries. <i>Nanoscale</i> , <b>2011</b> , 3, 4798-803	7.7	24
26	Surface charge transfer induced p-CdS nanoribbon/n-Si heterojunctions as fast-speed self-driven photodetectors. <i>Journal of Materials Chemistry C</i> , <b>2015</b> , 3, 6307-6313	7.1	22
25	Catalyst-Free VaporBolid Deposition Growth of EGa2O3 Nanowires for DUV Photodetector and Image Sensor Application. <i>Advanced Optical Materials</i> , <b>2019</b> , 7, 1901257	8.1	21
24	Defect-induced broadband photodetection of layered In2Se3 nanofilm and its application in near infrared image sensors. <i>Journal of Materials Chemistry C</i> , <b>2019</b> , 7, 11532-11539	7.1	20

23	Lasing Characteristics of CH3NH3PbCl3 Single-Crystal Microcavities under Multiphoton Excitation. <i>Advanced Optical Materials</i> , <b>2018</b> , 6, 1700992	8.1	18	
22	Self-Powered Filterless Narrow-Band p-n Heterojunction Photodetector for Low Background Limited Near-Infrared Image Sensor Application. <i>ACS Applied Materials &amp; Discrete Application</i> , 12, 218-	45 <sup>9</sup> 2 <sup>5</sup> 18:	53 <sup>18</sup>	
21	Highly Sensitive Narrowband Si Photodetector With Peak Response at Around 1060 nm. <i>IEEE Transactions on Electron Devices</i> , <b>2020</b> , 67, 3211-3214	2.9	15	
20	High-performance nonvolatile Al/AlO(x)/CdTe:Sb nanowire memory device. <i>Nanotechnology</i> , <b>2013</b> , 24, 355203	3.4	15	
19	Chlorine-Doped ZnSe Nanoribbons with Tunable n-Type Conductivity as High-Gain and Flexible Blue/UV Photodetectors. <i>ChemPlusChem</i> , <b>2012</b> , 77, 470-475	2.8	15	
18	Opening the Band Gap of Graphene via Fluorination for High-Performance Dual-Mode Photodetector Application. <i>ACS Applied Materials &amp; Discrete Faces</i> , <b>2019</b> , 11, 21702-21710	9.5	14	
17	A SERS stamp: Multiscale coupling effect of silver nanoparticles and highly ordered nano-micro hierarchical substrates for ultrasensitive explosive detection. <i>Sensors and Actuators B: Chemical</i> , <b>2020</b> , 321, 128543	8.5	13	
16	Fabrication of Addressable Perovskite Film Arrays for High-Performance Photodetection and Real-Time Image Sensing Application. <i>Journal of Physical Chemistry Letters</i> , <b>2021</b> , 12, 2930-2936	6.4	11	
15	High-Performance Blue-Light Photodetectors Based on Single-Crystal ZnSe Nanoribbons with Controlled Gallium Doping. <i>Science of Advanced Materials</i> , <b>2012</b> , 4, 332-336	2.3	9	
14	Photodetectors: Controlled Synthesis of 2D Palladium Diselenide for Sensitive Photodetector Applications (Adv. Funct. Mater. 1/2019). <i>Advanced Functional Materials</i> , <b>2019</b> , 29, 1970005	15.6	9	
13	Construction of PtSe/Ge heterostructure-based short-wavelength infrared photodetector array for image sensing and optical communication applications. <i>Nanoscale</i> , <b>2021</b> , 13, 7606-7612	7.7	8	
12	Characterization of structural transitions and lattice dynamics of hybrid organicihorganic perovskite CH3NH3PbI3. <i>Chinese Physics B</i> , <b>2019</b> , 28, 076102	1.2	7	
11	Controlled synthesis of GaSe microbelts for high-gain photodetectors induced by the electron trapping effect. <i>Journal of Materials Chemistry C</i> , <b>2020</b> , 8, 5375-5379	7.1	5	
10	Dual-plasmonic Au/graphene/Au-enhanced ultrafast, broadband, self-driven silicon Schottky photodetector. <i>Nanotechnology</i> , <b>2018</b> , 29, 505203	3.4	5	
9	Multilayered PtSe2/pyramid-Si heterostructure array with light confinement effect for high-performance photodetection, image sensing and light trajectory tracking applications. <i>Journal of Materials Chemistry C</i> , <b>2021</b> , 9, 2823-2832	7.1	5	
8	Multilayered PdTeIGaN Heterostructures for Visible-Blind Deep-Ultraviolet Photodetection. <i>IEEE Electron Device Letters</i> , <b>2021</b> , 42, 1192-1195	4.4	4	
7	High-performance light trajectory tracking and image sensing devices based on a £ln2Se3/GaAs heterostructure. <i>Journal of Materials Chemistry C</i> , <b>2020</b> , 8, 13762-13769	7.1	3	
6	Enhanced Light Trapping in Conformal CuO/Si Microholes Array Heterojunction for Self-Powered Broadband Photodetection. <i>IEEE Electron Device Letters</i> , <b>2021</b> , 42, 883-886	4.4	3	

5	Ultrawide-Bandgap Semiconductors: Recent Progress in Solar-Blind Deep-Ultraviolet Photodetectors Based on Inorganic Ultrawide Bandgap Semiconductors (Adv. Funct. Mater. 9/2019). <i>Advanced Functional Materials</i> , <b>2019</b> , 29, 1970057	15.6	2
4	Photodetectors: Fast, Self-Driven, Air-Stable, and Broadband Photodetector Based on Vertically Aligned PtSe2/GaAs Heterojunction (Adv. Funct. Mater. 16/2018). <i>Advanced Functional Materials</i> , <b>2018</b> , 28, 1870106	15.6	2
3	Distinguishing wavelength using two parallelly stacking graphene/thin Si/graphene heterojunctions. <i>Journal of Materials Chemistry C</i> ,	7.1	2
2	Ti3C2Tx MXene/Ge 2D/3D van der Waals heterostructures as highly efficient and fast response near-infrared photodetectors. <i>Applied Physics Letters</i> , <b>2022</b> , 120, 141103	3.4	2
1	Fabrication of a 🛘 n2Se3/Si heterostructure phototransistor for heart rate detection. <i>Journal of Materials Chemistry C</i>	7.1	